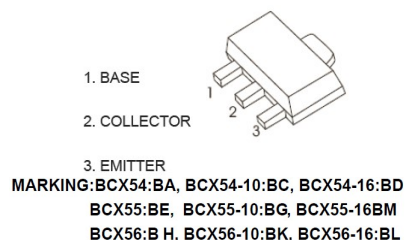


SOT-89-3L



SOT-89-3L 贴片塑封三极管 SOT-89-3L Plastic-Encapsulate Transistors

特征 Features

- 与 BCX51, BCX52, BCX53 配对; Complementary to BCX51, BCX52, BCX53
- 最大功率耗散 500mW; Power Dissipation of 500mW
- 高稳定性和可靠性。High Stability and High Reliability

机械数据 Mechanical Data

- 封装: SOT-89-3L 封装 SOT-89-3L Small Outline Plastic Package
- 环氧树脂 UL 易燃等级 Epoxy UL: 94V-0
- 安装位置: 任意 Mounting Position: Any

极限值和温度特性(TA = 25°C 除非另有规定)

Maximum Ratings & Thermal Characteristics (Ratings at 25°C ambient temperature unless otherwise specified.)

参数 Parameters	符号 Symbol	TYPE	数值 Value	单位 Unit
Collector-Base Voltage	V _{CBO}	BCX54 BCX55 BCX56	45 60 100	V
Collector-Emitter Voltage	V _{CEO}	BCX54 BCX55 BCX56	45 60 80	V
Emitter -Base Voltage	V _{EBO}		5	V
Collector Current-Continuous	I _C		1.0	A
Base Curren	I _B		0.1	A
Collector Power Dissipation	P _C		500	mW
Junction Temperature	T _j		150	°C
Storage Temperature	T _{stg}		-55-+150	°C
Thermal resistance From junction to ambient	R _{θJA}		250	°C/W

电特性 (TA = 25°C 除非另有规定)

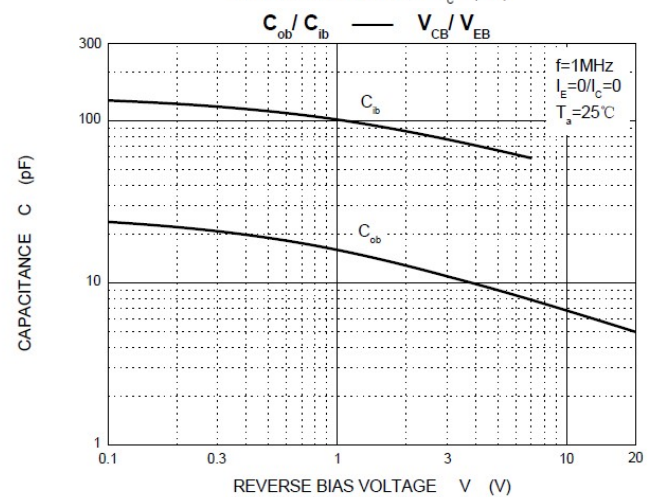
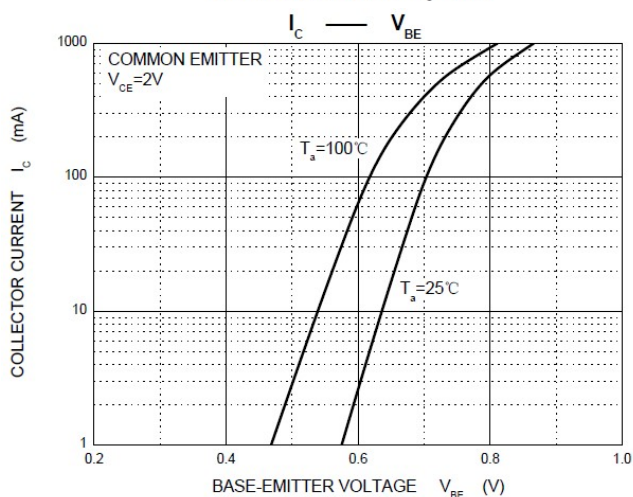
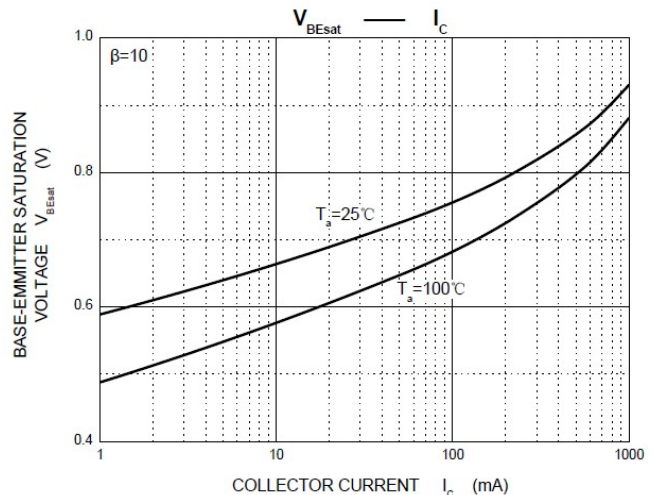
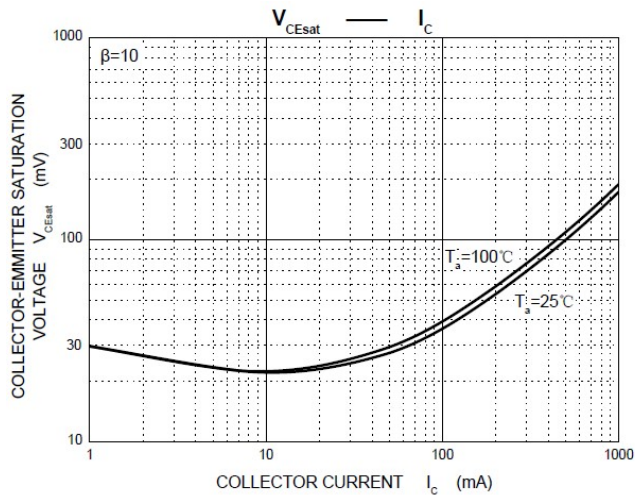
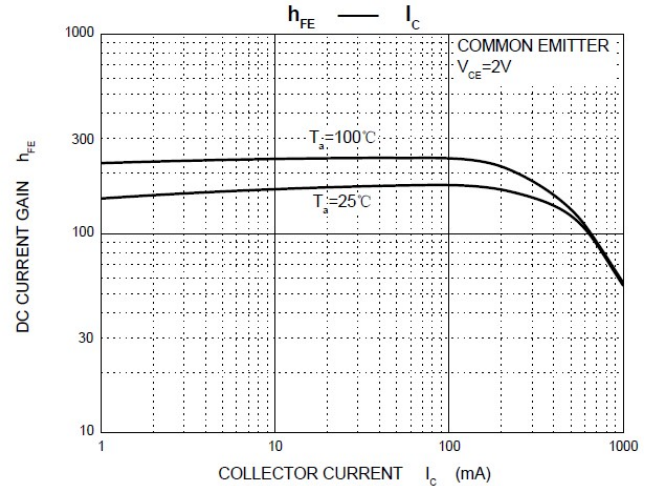
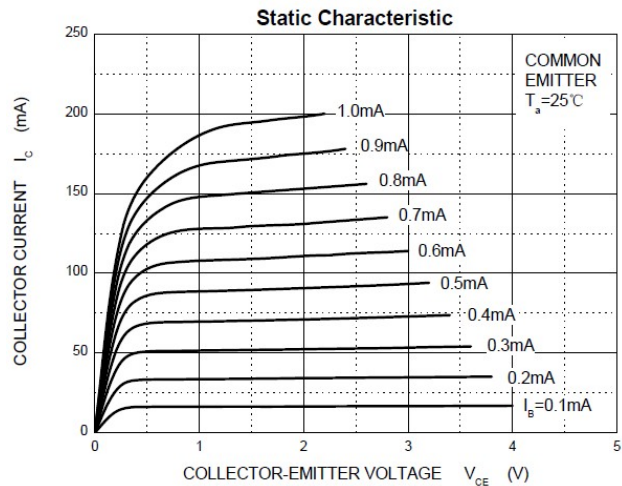
Electrical Characteristics (Ratings at 25°C ambient temperature unless otherwise specified).

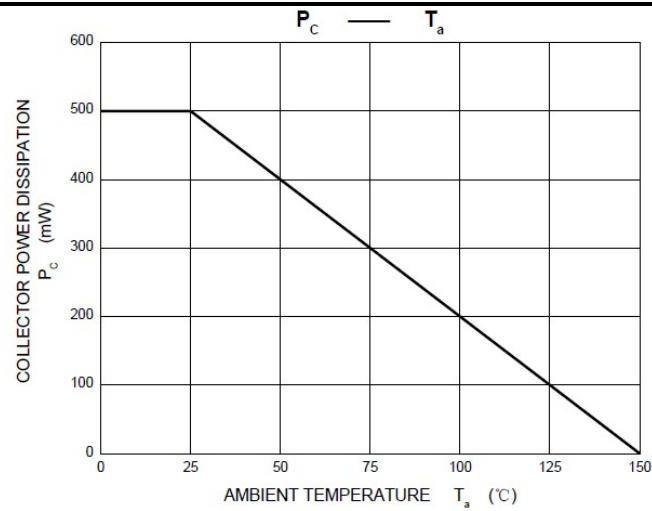
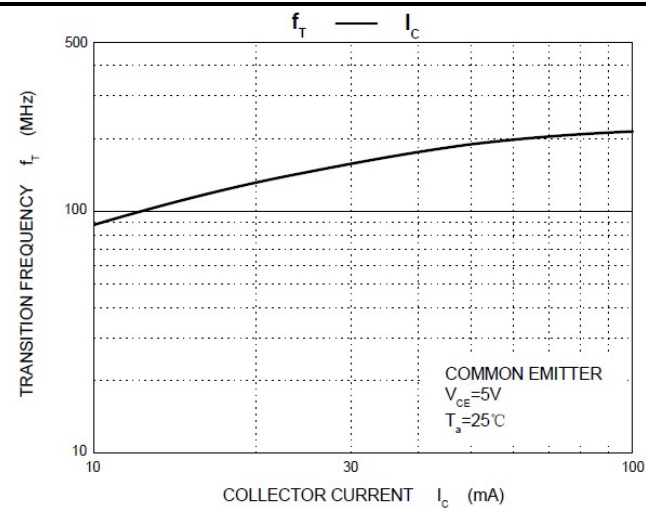
参数 Parameter	符号 Symbols	测试条件 Test Condition	界限 Limits			单位 Unit
			Min	Typ	Max	
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =100uA, I _E =0	BCX54 45 BCX55 60 BCX56 100			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =10mA, I _B =0	BCX54 45 BCX55 60 BCX56 80			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =10uA, I _C =0	5			V
Collector cut-off current	I _{CBO}	V _{CB} =30V, I _E =0			100	nA
Emitter cut-off current	I _{EBO}	V _{EB} =5V, I _C =0			100	nA
DC current gain	h _{FE} (1)	V _{CE} =2V, I _C =5mA	40			
	h _{FE} (2)	V _{CE} =2V, I _C =150mA	63		250	
	h _{FE} (3)	V _{CE} =2V, I _C =500mA	25			
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =500mA, I _B =50mA			0.50	V
Base -emitter voltage	V _{BE}	V _{CE} =2V, I _C =500mA			1.00	V
Transition frequency	f _T	V _{CE} =5V, I _C =10mA, f=100MHz		130		MHz

CLASSIFICATION OF h_{FE}(2)

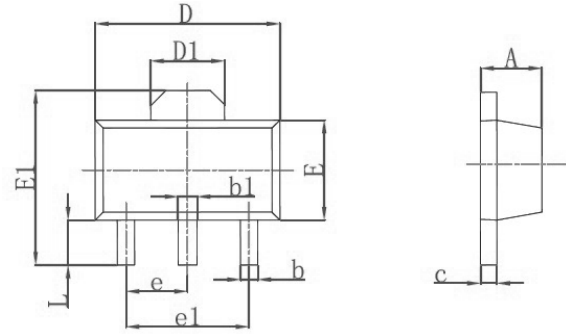
RANK	BCX54 BCX55 BCX56	BCX54-10 BCX55-10 BCX56-10	BCX54-16 BCX55-16 BCX56-16
RANGE	63-250	63-160	100-250

Typical characteristics



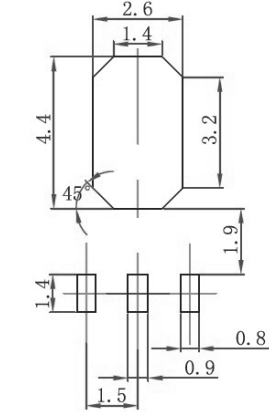


SOT-89-3L PACKAGE OUTLINE Plastic surface mounted package



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF.		0.061 REF.	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500 TYP.		0.060 TYP.	
e1	3.000 TYP.		0.118 TYP.	
L	0.900	1.200	0.035	0.047

焊盘设计参考Precautions: PCB Design
Recommended land dimensions for SOT-89-3L diode. Electrode patterns for PCBs



Note:
1.Controlling dimension:in millimeters.
2.General tolerance:±0.05mm.
3.The pad layout ls for reference purposes only.